

# 2SK1169, 2SK1170

Silicon N-Channel MOS FET

# HITACHI

ADE-208-1254 (Z)

1st. Edition

Mar. 2001

## Application

High speed power switching

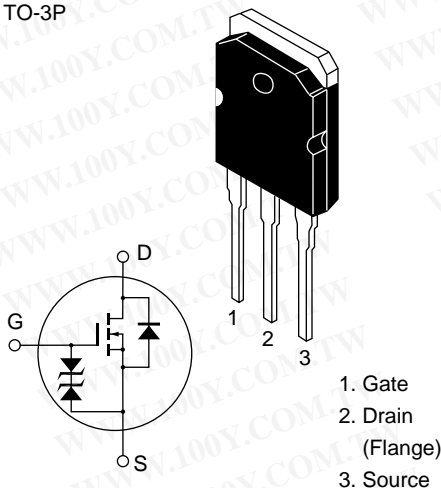
## Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator and DC-DC converter

## Outline

勝特力材料 886-3-5753170  
勝特力电子(上海) 86-21-54151736  
勝特力电子(深圳) 86-755-83298787  
[Http://www.100y.com.tw](http://www.100y.com.tw)

TO-3P



## 2SK1169, 2SK1170

### Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Ratings	Unit
Drain to source voltage	2SK1169	$V_{DSS}$	450	V
	2SK1170		500	
Gate to source voltage		$V_{GSS}$	±30	V
Drain current		$I_D$	20	A
Drain peak current		$I_{D(pulse)}^{*1}$	80	A
Body to drain diode reverse drain current		$I_{DR}$	20	A
Channel dissipation		$P_{ch}^{*2}$	120	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW 10  $\mu$ s, duty cycle 1%

2. Value at T<sub>c</sub> = 25°C

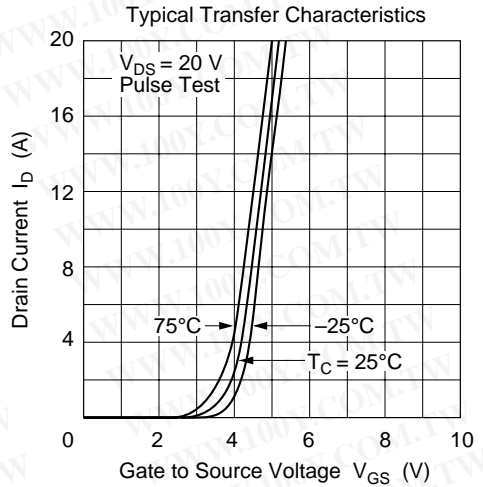
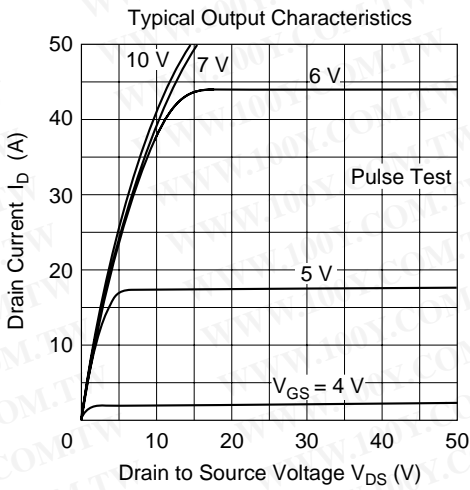
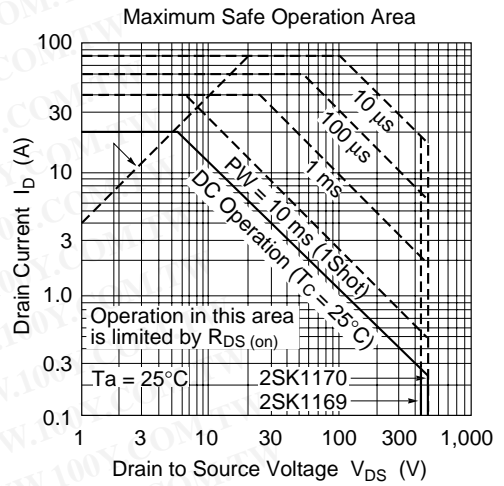
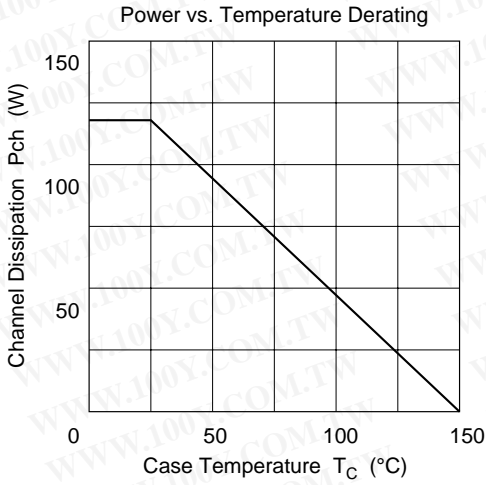
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## Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	2SK1169 $V_{(BR)DSS}$ 2SK1170	450 500	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±30	—	—	V	$I_G = \pm 100 \mu\text{A}$ , $V_{DS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	±10	μA	$V_{GS} = \pm 25 \text{ V}$ , $V_{DS} = 0$
Zero gate voltage drain current	2SK1169 $I_{DSS}$ 2SK1170	—	—	250	μA	$V_{DS} = 360 \text{ V}$ , $V_{GS} = 0$ $V_{DS} = 400 \text{ V}$ , $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	3.0	V	$I_D = 1 \text{ mA}$ , $V_{DS} = 10 \text{ V}$
Static Drain to source on state resistance	2SK1169 $R_{DS(on)}$ 2SK1170	—	0.20 0.22	0.25 0.27		$I_D = 10 \text{ A}$ , $V_{GS} = 10 \text{ V}^{*1}$
Forward transfer admittance	yfs	10	16	—	S	$I_D = 10 \text{ A}$ , $V_{DS} = 10 \text{ V}^{*1}$
Input capacitance	Ciss	—	2800	—	pF	$V_{DS} = 10 \text{ V}$ , $V_{GS} = 0$ ,
Output capacitance	Coss	—	780	—	pF	f = 1 MHz
Reverse transfer capacitance	Crss	—	90	—	pF	
Turn-on delay time	$t_{d(on)}$	—	32	—	ns	$I_D = 10 \text{ A}$ , $V_{GS} = 10 \text{ V}$ ,
Rise time	$t_r$	—	115	—	ns	$R_L = 3$
Turn-off delay time	$t_{d(off)}$	—	200	—	ns	
Fall time	$t_f$	—	90	—	ns	
Body to drain diode forward voltage	$V_{DF}$	—	1.0	—	V	$I_F = 20 \text{ A}$ , $V_{GS} = 0$
Body to drain diode reverse recovery time	$t_{rr}$	—	500	—	ns	$I_F = 20 \text{ A}$ , $V_{GS} = 0$ , $di_F/dt = 100 \text{ A}/\mu\text{s}$

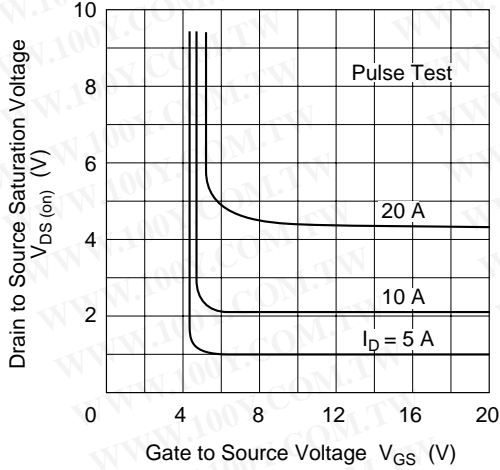
Note: 1. Pulse test

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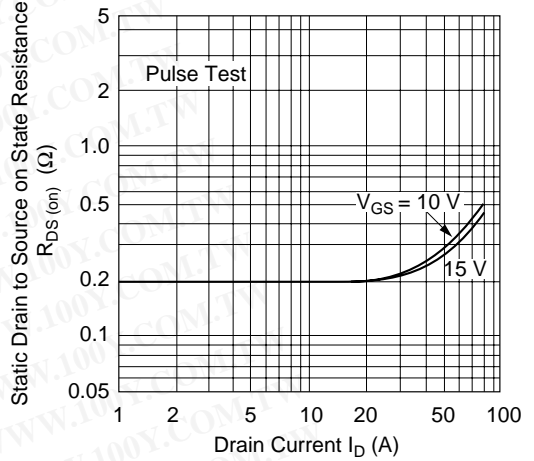


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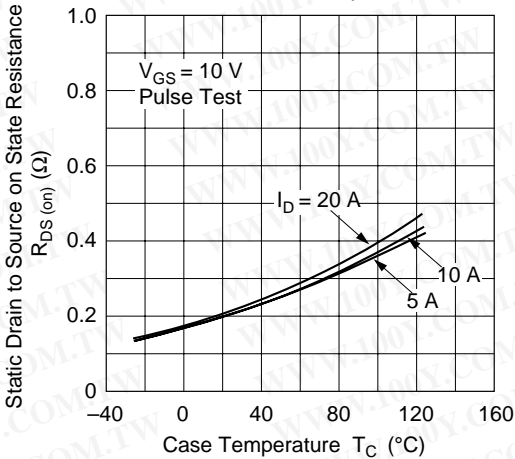
Drain to Source Saturation Voltage vs. Gate to Source Voltage



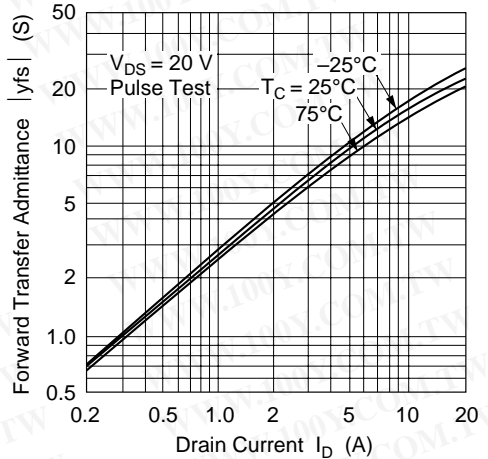
Static Drain to Source on State Resistance vs. Drain Current



Static Drain to Source on State Resistance vs. Temperature

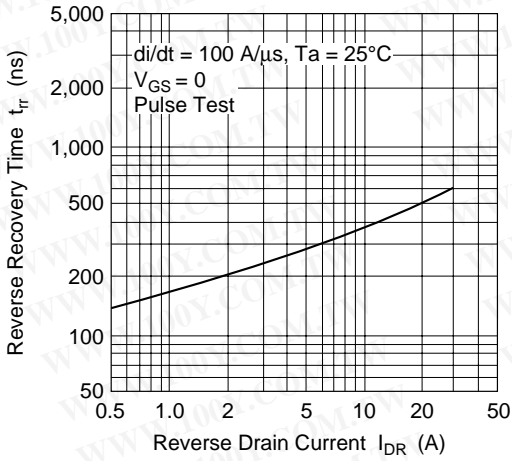


Forward Transfer Admittance vs. Drain Current

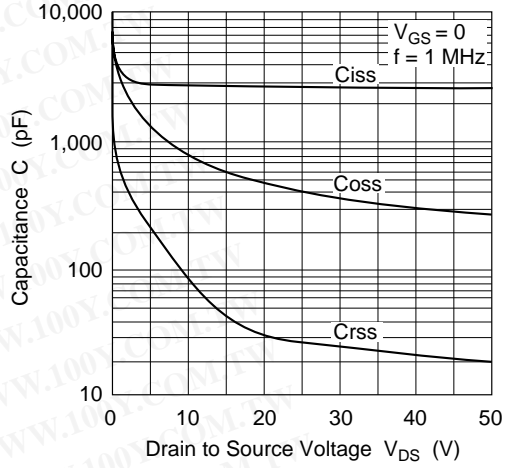


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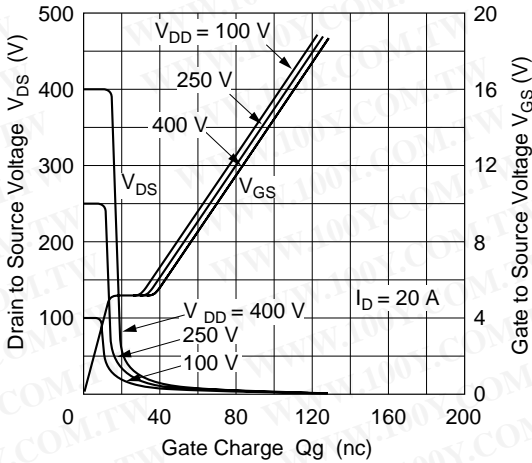
Body to Drain Diode Reverse Recovery Time



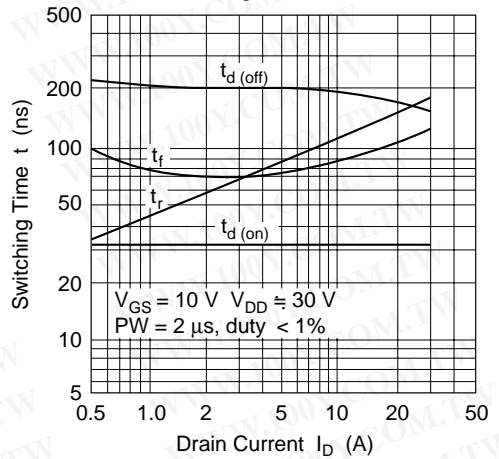
Typical Capacitance vs. Drain to Source Voltage



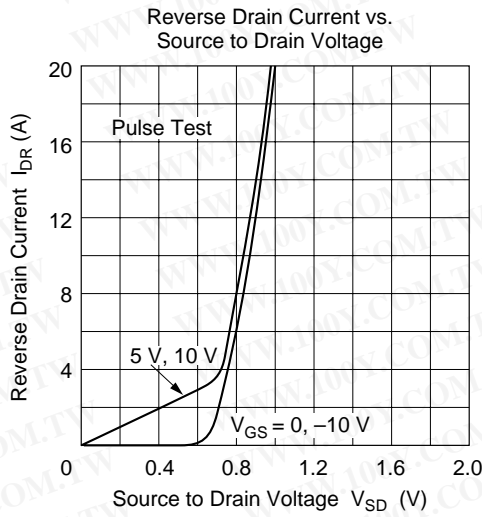
Dynamic Input Characteristics



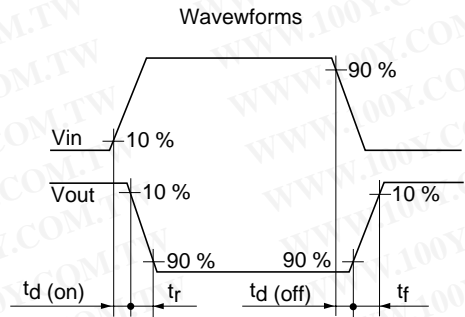
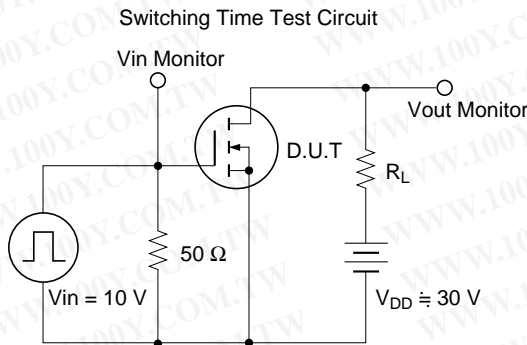
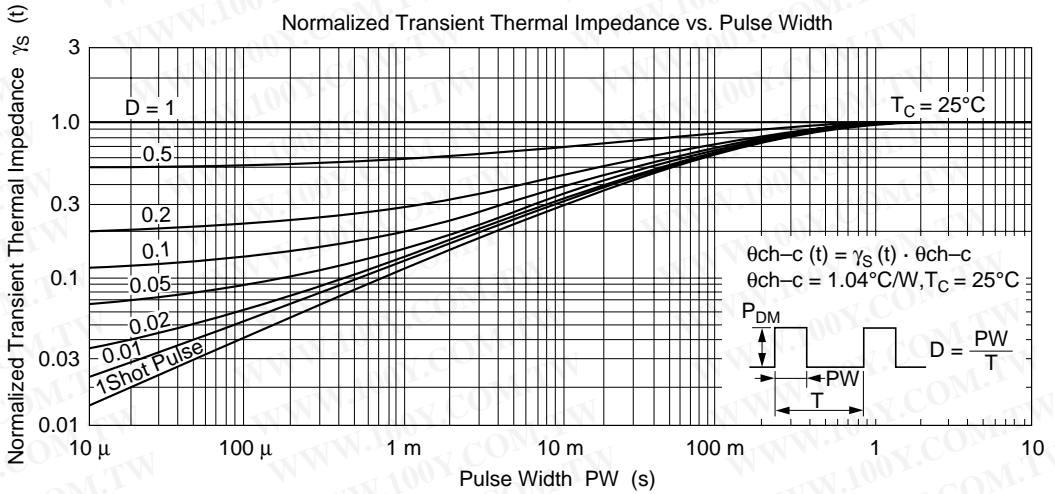
Switching Characteristics



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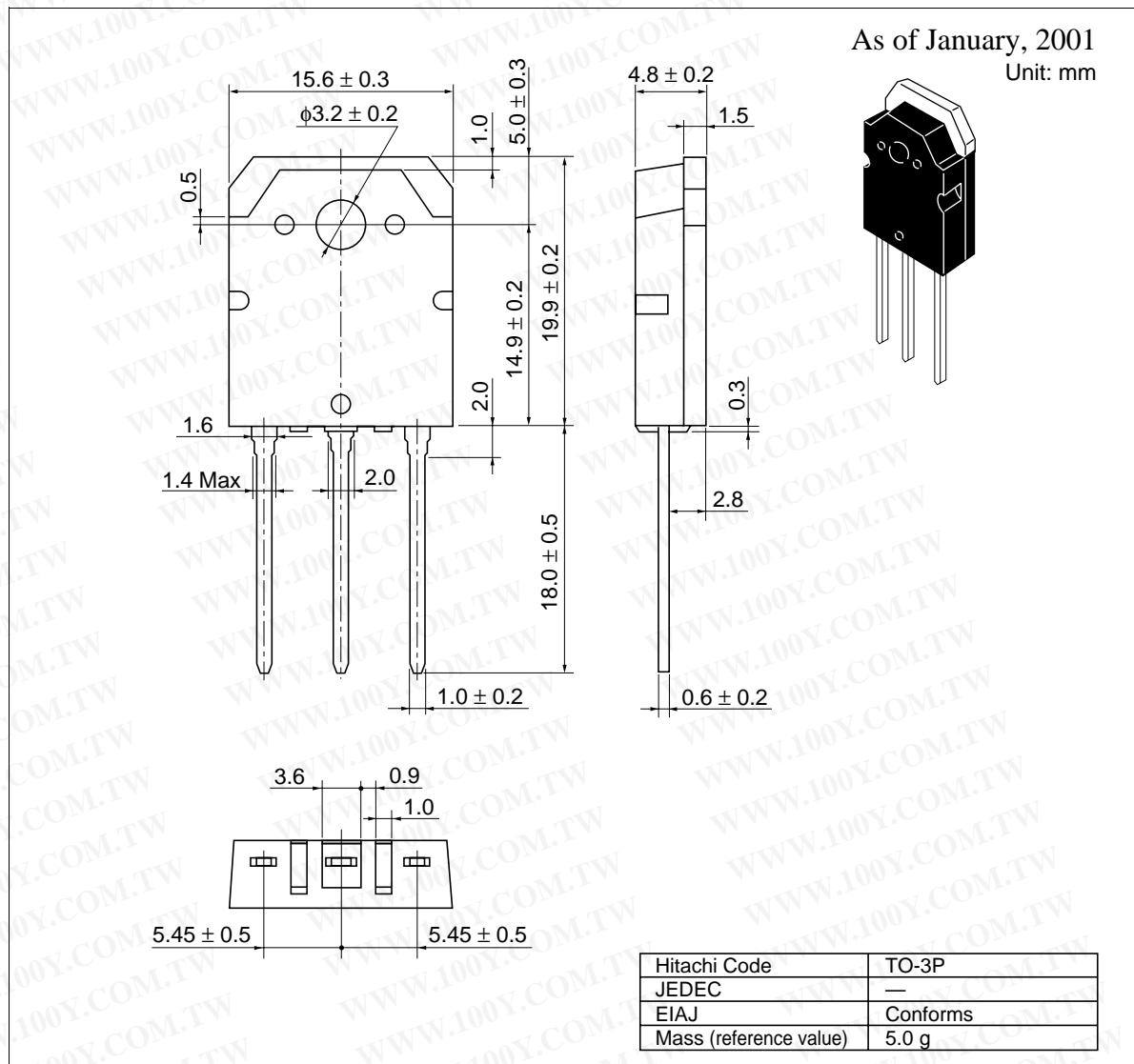


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# 2SK1169, 2SK1170

## Package Dimensions



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